

Hyper 3 mm (T1) LED, Diffused Hyper-Bright, Wide-Angle LED

LS 3386, LA 3386, LO 3386, LY 3386



Besondere Merkmale

- **Gehäusotyp:** eingefärbtes, diffuses 3 mm (T1) Gehäuse
- **Besonderheit des Bauteils:** Lötspieße mit Aufsetzebene
- **Wellenlänge:** 633 nm (super-rot), 615 nm (amber), 606 nm (orange), 587 nm (gelb)
- **Abstrahlwinkel:** 100°
- **Technologie:** InGaAlP
- **optischer Wirkungsgrad:** 11 lm/W (gelb, orange, amber), 7 lm/W (super-rot)
- **Gruppierungsparameter:** Lichtstärke
- **Lötmethode:** Wellenlöten (TTW)
- **Vorbehandlung:** nach JEDEC Level 2
- **Verpackung:** Schüttgut, gegurtet lieferbar

Anwendungen

- optischer Indikator
- Hinterleuchtung (Tasten, Displays, Werbebeleuchtung, Allgemeinbeleuchtung)
- Innenbeleuchtung im Automobilbereich (z.B. Tastenbeleuchtung, u.ä.)
- Markierungsbeleuchtung (z.B. Stufen, Fluchtwege, u.ä.)
- Signal- und Symbolleuchten

Features

- **package:** colored, diffused 3 mm (T1) package
- **feature of the device:** solder leads with stand-off
- **wavelength:** 633 nm (super-red), 615 nm (amber), 606 nm (orange), 587 nm (yellow)
- **viewing angle:** 100°
- **technology:** InGaAlP
- **optical efficiency:** 11 lm/W (yellow, orange, amber), 7 lm/W (super-red)
- **grouping parameter:** luminous intensity
- **soldering methods:** TTW soldering
- **preconditioning:** acc. to JEDEC Level 2
- **packing:** bulk, available taped on reel

Applications

- coupling into light guides
- backlighting (keys, displays, illuminated advertising, general lighting)
- interior automotive lighting (e.g. key backlighting, etc.)
- marker lights (e.g. steps, exit ways, etc.)
- signal and symbol luminaire

Type	Emissions- farbe Color of Emission	Gehäuse- farbe Color of Package	Lichtstärke Luminous Intensity $I_F = 20 \text{ mA}$ $I_V \text{ (mcd)}$	Lichtstrom Luminous Flux $I_F = 20 \text{ mA}$ $\Phi_V \text{ (lm)}$	Bestellnummer Ordering Code
LS 3386-LP	super-red	red diffused	11.2 ... 71.0	360 (typ.)	Q62703-Q3579
LS 3386-M			18.0 ... 28.0	190 (typ.)	Q62703-Q3581
LS 3386-N			28.0 ... 45.0	300 (typ.)	Q62703-Q3582
LS 3386-P			45.0 ... 71.0	480 (typ.)	Q62703-Q3709
LS 3386-MQ			18.0 ... 112.0	560 (typ.)	Q62703-Q3580
LA 3386-MQ	amber	orange diffused	18.0 ... 112.0	530 (typ.)	Q62703-Q3886
LA 3386-N			28.0 ... 45.0	280 (typ.)	Q62703-Q3887
LA 3386-P			45.0 ... 71.0	450 (typ.)	Q62703-Q3888
LA 3386-Q			71.0 ... 112.0	700 (typ.)	Q62703-Q3889
LA 3386-NR			28.0 ... 180.0	840 (typ.)	Q62703-Q3890
■ LO 3386-MQ	orange	orange diffused	18.0 ... 112.0	530 (typ.)	Q62703-Q3891
■ LO 3386-N			28.0 ... 45.0	280 (typ.)	Q62703-Q3892
■ LO 3386-P			45.0 ... 71.0	450 (typ.)	Q62703-Q3893
■ LO 3386-Q			71.0 ... 112.0	700 (typ.)	Q62703-Q3894
■ LO 3386-NR			28.0 ... 180.0	840 (typ.)	Q62703-Q3895
LY 3386-MQ	yellow	yellow diffused	18.0 ... 112.0	530 (typ.)	Q62703-Q3896
LY 3386-N			28.0 ... 45.0	280 (typ.)	Q62703-Q3897
LY 3386-P			45.0 ... 71.0	450 (typ.)	Q62703-Q3898
LY 3386-Q			71.0 ... 112.0	700 (typ.)	Q62703-Q3899
LY 3386-NR			28.0 ... 180.0	840 (typ.)	Q62703-Q3900

■ Nicht für Neuentwicklungen/ Not for new designs

Helligkeitswerte werden mit einer Stromeinprägedauer von 25 ms und einer Genauigkeit von $\pm 11 \%$ ermittelt.
Luminous intensity is tested at a current pulse duration of 25 ms and a tolerance of $\pm 11 \%$.

Anm.: Die Standardlieferform von Serientypen beinhaltet eine untere bzw. eine obere Familiengruppe oder mindestens zwei Einzelgruppen.

In einer Verpackungseinheit / Gurt ist immer nur eine Helligkeitsgruppe enthalten.

Die technologiebedingte Helligkeits-Streuung der heutigen LED-Herstellprozesse über einen längeren Fertigungszeitraum (Halbleitermaterial - Chipherstellung - Montageprozess) erlaubt keine Zusage einer einzelnen Helligkeitsgruppe. Daher müssen mindestens zwei Helligkeitsgruppen vorgesehen werden!

Note: The standard shipping format for serial types includes a lower or upper family group or at least two individual groups.

No packing unit / tape ever contains more than one luminous intensity group.

Luminosity variations caused by the technology used in current LED manufacturing processes over a protracted manufacturing period (semiconductor material - chip fabrication - assembly process) mean that it is not possible to assign LEDs to a single luminous intensity group. For this reason at least two luminous intensity groups must be provided!

Grenzwerte
Maximum Ratings

Bezeichnung Parameter	Symbol Symbol	Werte Values		Einheit Unit
		LS, LO, LA	LY	
Betriebstemperatur Operating temperature range	T_{op}	– 55 ... + 100		°C
Lagertemperatur Storage temperature range	T_{stg}	– 55 ... + 100		°C
Sperrschichttemperatur Junction temperature	T_j	+ 100		°C
Durchlassstrom Forward current	I_F	30		mA
Stoßstrom Surge current $t \leq 10 \mu s, D = 0.005$	I_{FM}	1	0.2	A
Sperrspannung Reverse voltage	V_R	3		V
Leistungsaufnahme Power consumption $T_A \leq 25 \text{ °C}$	P_{tot}	80		mW
Wärmewiderstand ¹⁾ Thermal resistance Sperrschicht/Umgebung Junction/ambient Sperrschicht/Löt看 Junction/solder point Montage auf PC-Board FR 4 (Padgröße $\geq 16 \text{ mm}^2$) mounted on PC board FR 4 (pad size $\geq 16 \text{ mm}^2$) Minimale Beinchenlänge Minimum lead length	$R_{th JA}$ $R_{th JS}$	500 280		K/W K/W

¹⁾ R_{th} erhöht sich um 13 K/W pro mm Beinchenlänge.
Each additional 1 mm of lead length increases R_{th} by 13 K/W.

Kennwerte ($T_A = 25\text{ °C}$)
Characteristics

Bezeichnung Parameter	Symbol Symbol	Werte Values				Einheit Unit
		LS	LA	LO	LY	
Wellenlänge des emittierten Lichtes (typ.) Wavelength at peak emission $I_F = 20\text{ mA}$	λ_{peak}	645	622	610	591	nm
Dominantwellenlänge (typ.) Dominant wavelength $I_F = 20\text{ mA}$	λ_{dom}	633	615	606	587	nm
Spektrale Bandbreite bei 50 % $I_{\text{rel max}}$ (typ.) Spectral bandwidth at 50 % $I_{\text{rel max}}$ $I_F = 20\text{ mA}$	$\Delta\lambda$	16	16	16	15	nm
Abstrahlwinkel bei 50 % I_V (Vollwinkel) (typ.) Viewing angle at 50 % I_V	2ϕ	100	100	100	100	Grad deg.
Durchlassspannung ¹⁾ (typ.) Forward voltage ¹⁾ (max.) $I_F = 20\text{ mA}$	V_F V_F	2.0 2.4	2.0 2.4	2.0 2.4	2.0 2.4	V V
Sperrstrom (typ.) Reverse current (max.) $V_R = 3\text{ V}$	I_R I_R	0.01 10	0.01 10	0.01 10	0.01 10	μA μA
Temperaturkoeffizient von λ_{peak} (typ.) Temperature coefficient of λ_{peak} $I_F = 20\text{ mA}; -10^\circ\text{C} \leq T \leq 100^\circ\text{C}$	$TC_{\lambda_{\text{peak}}}$	0.14	0.13	0.13	0.13	nm/K
Temperaturkoeffizient von λ_{dom} (typ.) Temperature coefficient of λ_{dom} $I_F = 20\text{ mA}; -10^\circ\text{C} \leq T \leq 100^\circ\text{C}$	$TC_{\lambda_{\text{dom}}}$	0.01	0.06	0.07	0.10	nm/K
Temperaturkoeffizient von V_F (typ.) Temperature coefficient of V_F $I_F = 20\text{ mA}; -10^\circ\text{C} \leq T \leq 100^\circ\text{C}$	TC_V	-2.0	-1.8	-1.7	-2.5	mV/K
Optischer Wirkungsgrad (typ.) Optical efficiency $I_F = 20\text{ mA}$	η_{opt}	7	11	11	11	lm/W

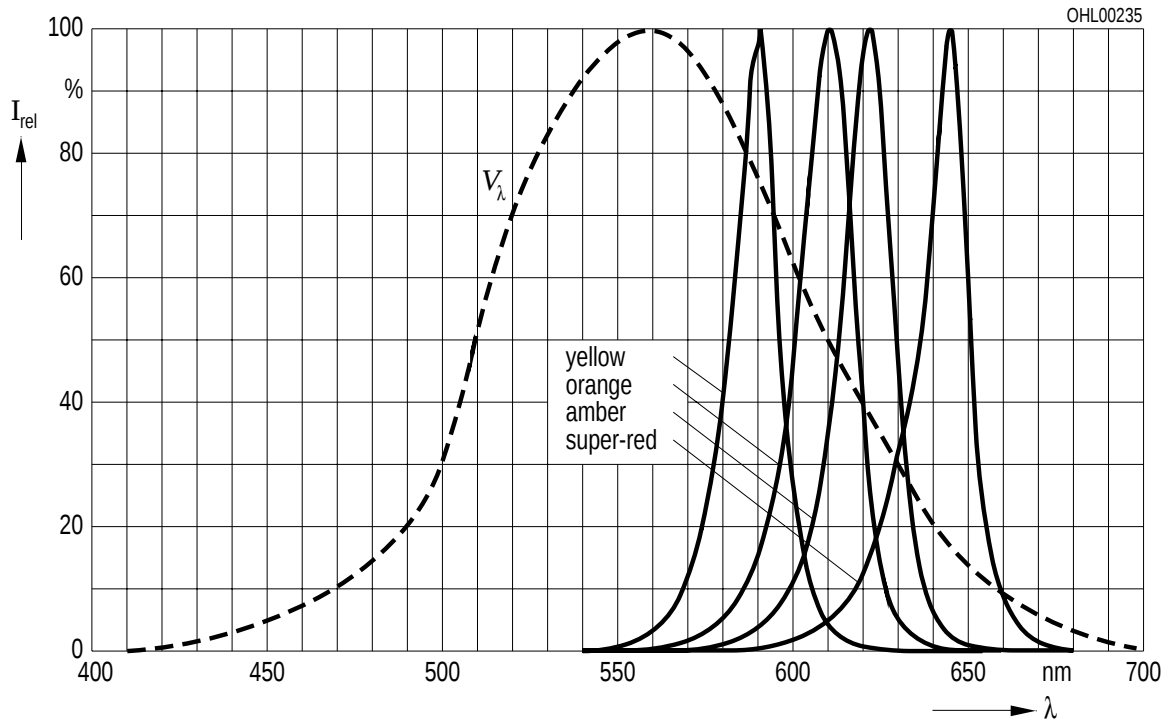
¹⁾ Spannungswerte werden mit einer Stromeinprägungsdauer von 1 ms und einer Genauigkeit von $\pm 0,1\text{ V}$ ermittelt.
Voltages are tested at a current pulse duration of 1 ms and a tolerance of $\pm 0.1\text{ V}$.

Relative spektrale Emission $I_{\text{rel}} = f(\lambda)$, $T_A = 25^\circ\text{C}$, $I_F = 20\text{ mA}$

Relative Spectral Emission

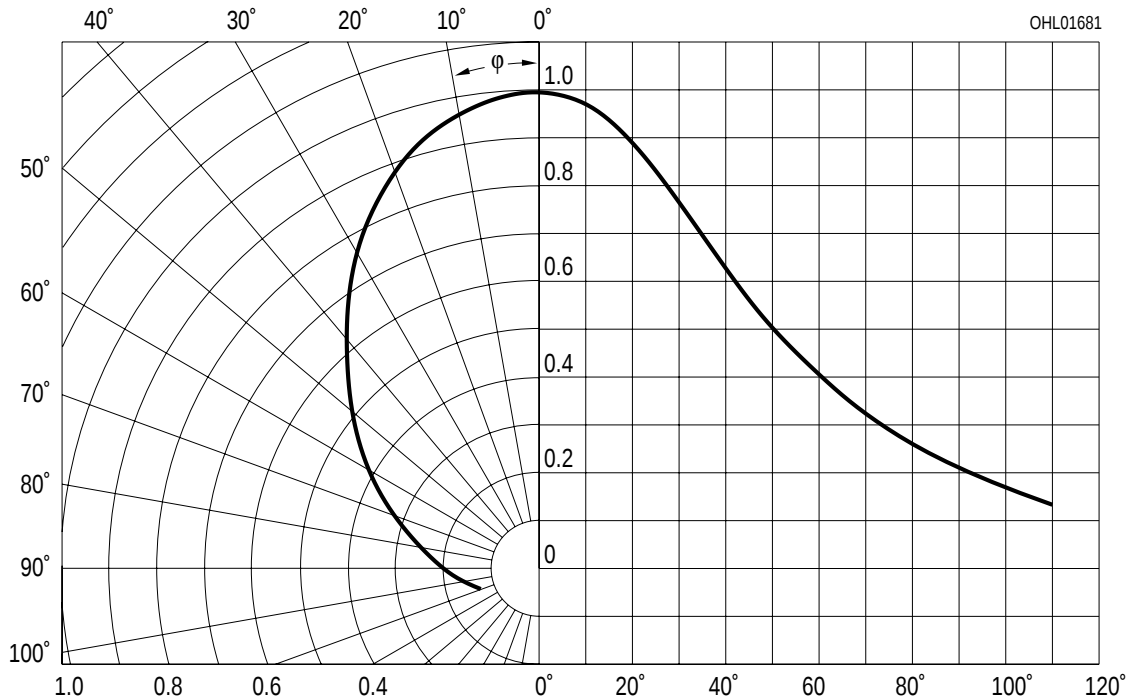
$V(\lambda)$ = spektrale Augenempfindlichkeit

Standard eye response curve



Abstrahlcharakteristik $I_{\text{rel}} = f(\varphi)$

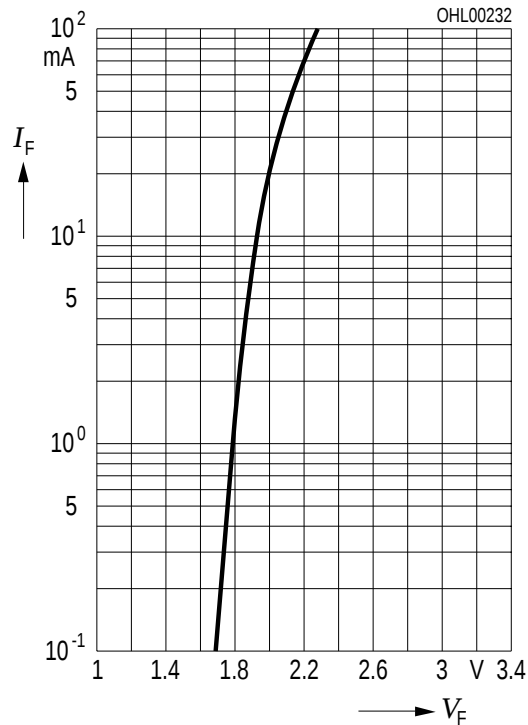
Radiation Characteristic



Durchlassstrom $I_F = f(V_F)$

Forward Current

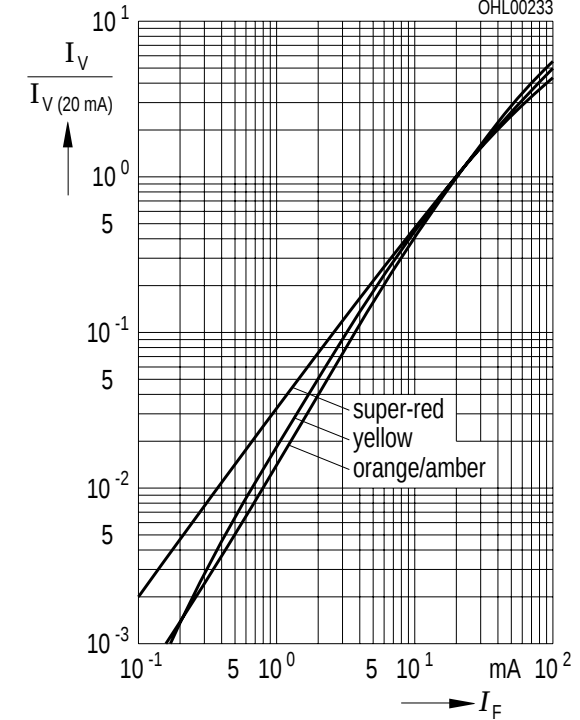
$T_A = 25^\circ\text{C}$



Relative Lichtstärke $I_V/I_{V(20\text{ mA})} = f(I_F)$

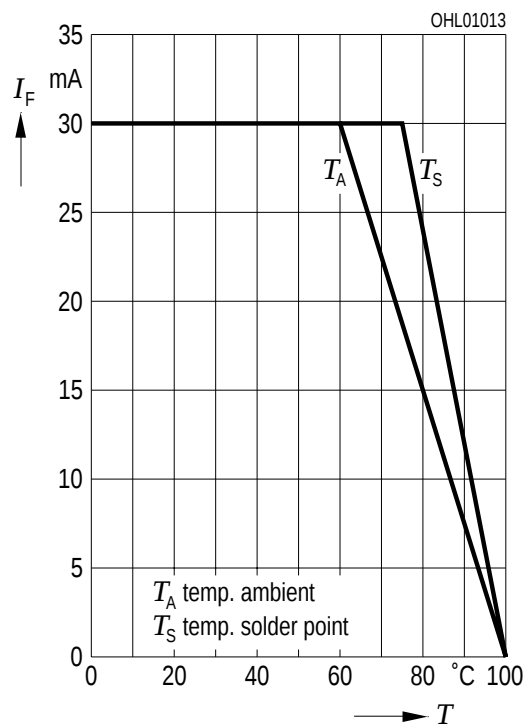
Relative Luminous Intensity

$T_A = 25^\circ\text{C}$



Maximal zulässiger Durchlassstrom $I_F = f(T)$

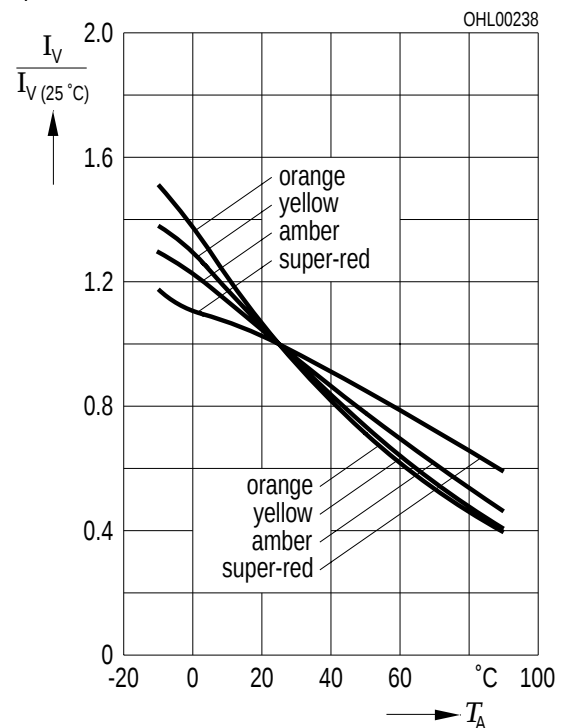
Max. Permissible Forward Current



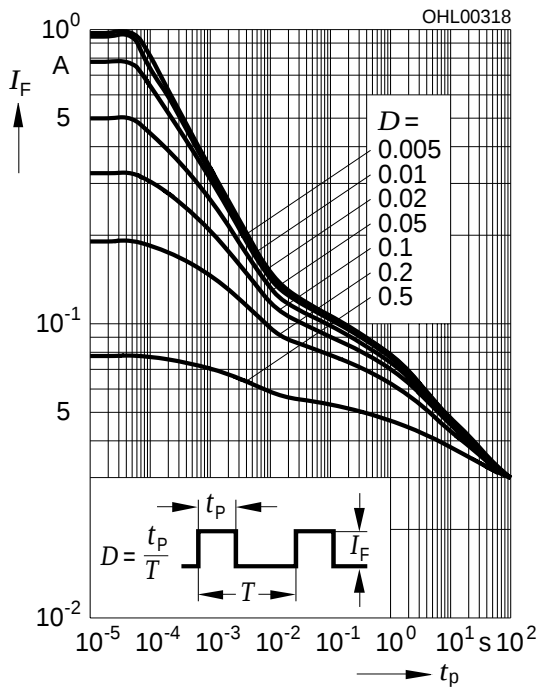
Relative Lichtstärke $I_V/I_{V(25^\circ\text{C})} = f(T_A)$

Relative Luminous Intensity

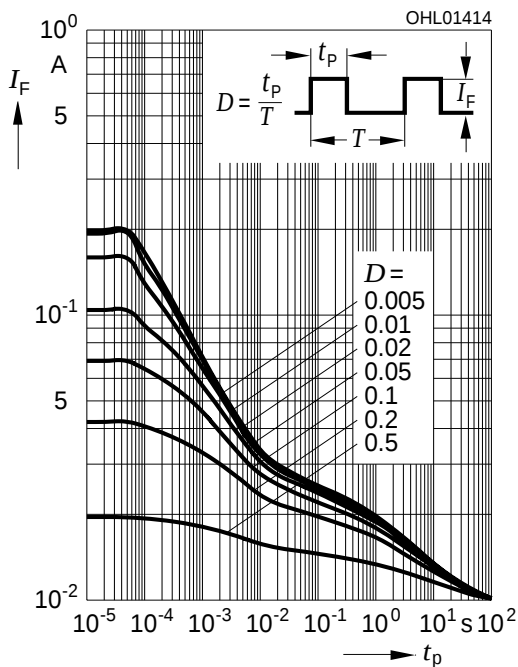
$I_F = 20\text{ mA}$



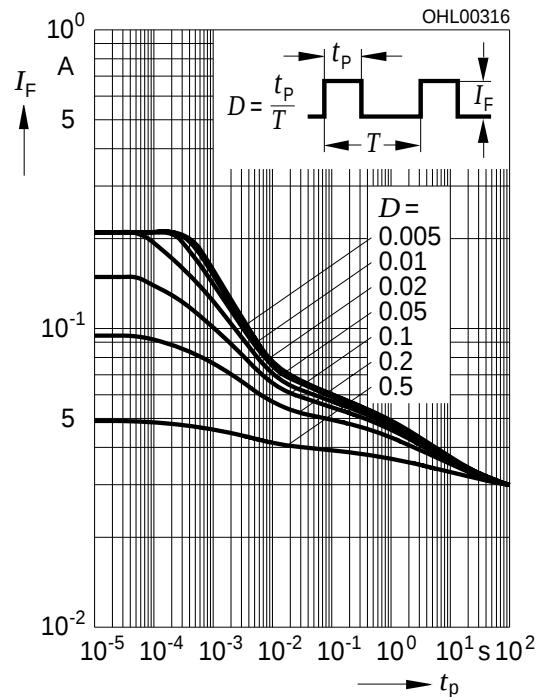
Zulässige Impulsbelastbarkeit $I_F = f(t_p)$
Permissible Pulse Handling Capability
Duty cycle $D =$ parameter, $T_A = 25\text{ °C}$
LS, LA, LO



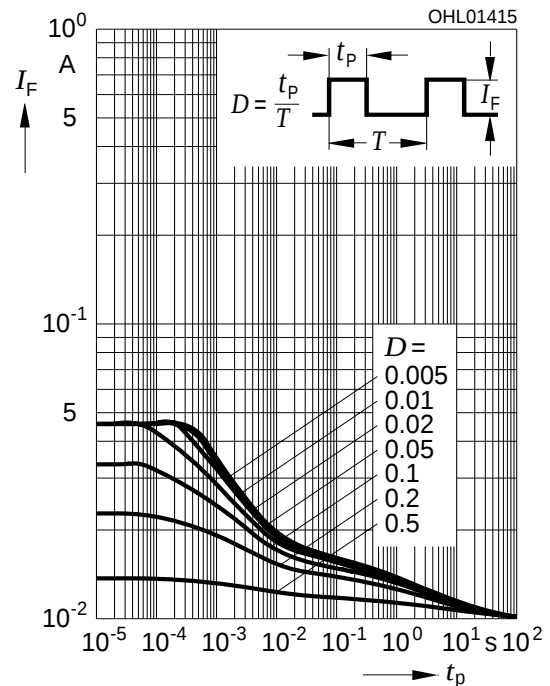
Zulässige Impulsbelastbarkeit $I_F = f(t_p)$
Permissible Pulse Handling Capability
Duty cycle $D =$ parameter, $T_A = 85\text{ °C}$
LS, LA, LO



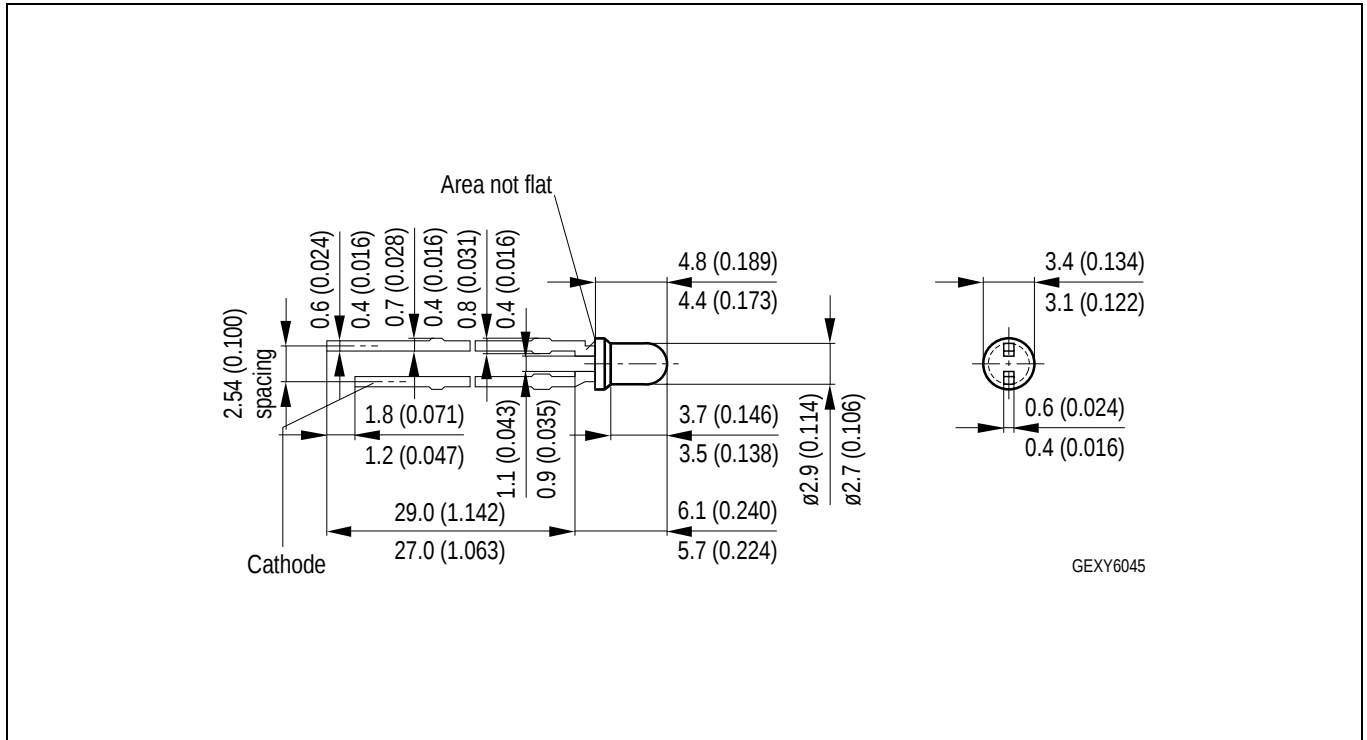
Zulässige Impulsbelastbarkeit $I_F = f(t_p)$
Permissible Pulse Handling Capability
Duty cycle $D =$ parameter, $T_A = 25\text{ °C}$
LY



Zulässige Impulsbelastbarkeit $I_F = f(t_p)$
Permissible Pulse Handling Capability
Duty cycle $D =$ parameter, $T_A = 85\text{ °C}$
LY



Maßzeichnung Package Outlines

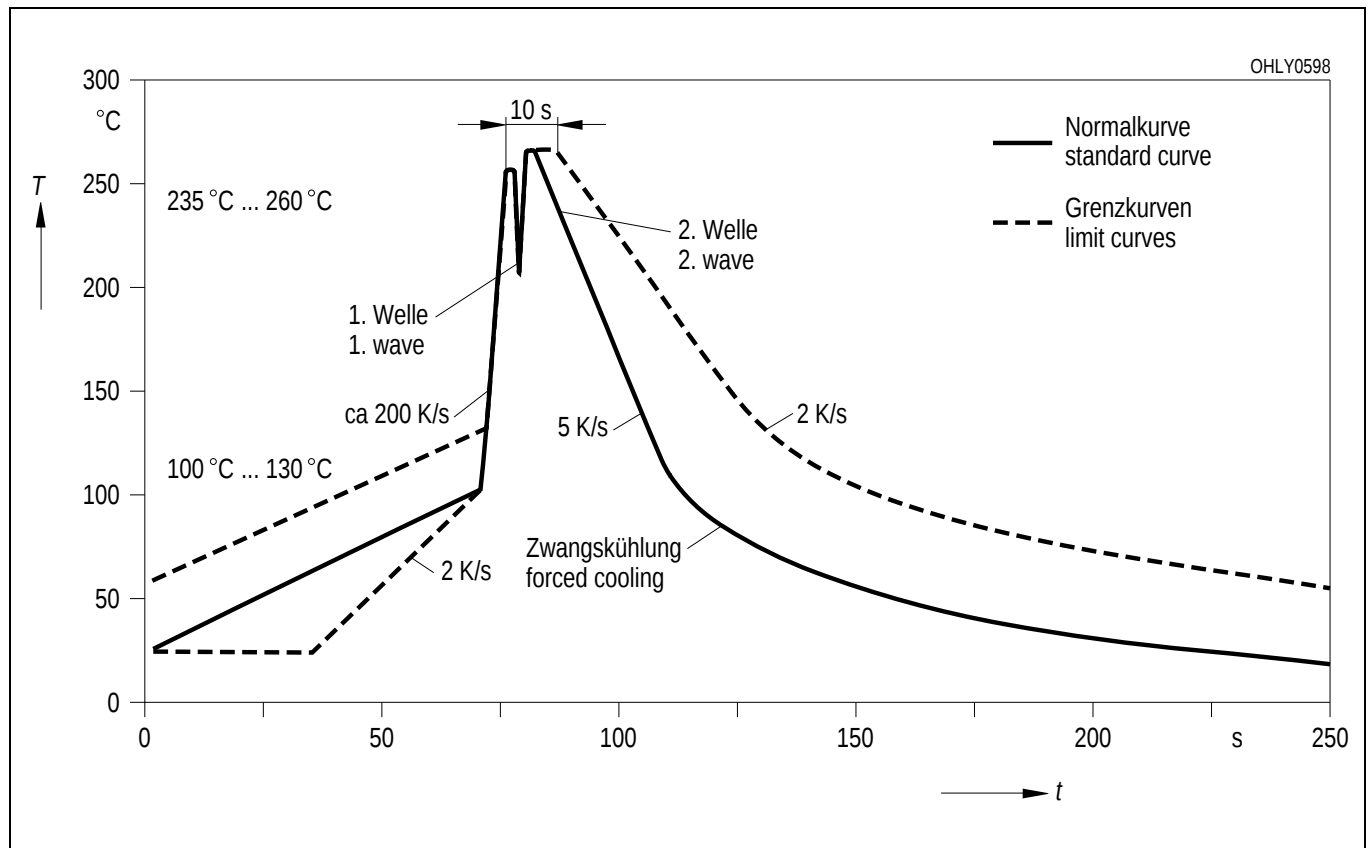


Maße werden wie folgt angegeben: mm (inch) / Dimensions are specified as follows: mm (inch).

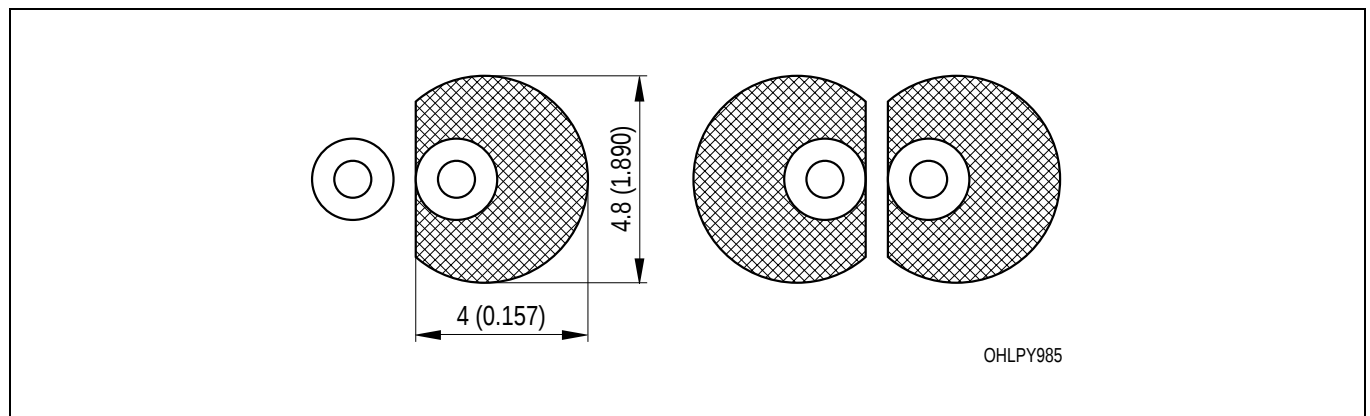
Kathodenkennung: kürzerer Lötspieß
Cathode mark: short solder lead
Gewicht / Approx. weight: 0.15 g

Lötbedingungen Soldering Conditions

Wellenlöten (TTW) (nach CECC 00802)
TTW Soldering (acc. to CECC 00802)



Empfohlenes Lötpaddesign Wellenlöten (TTW)
Recommended Solder Pad TTW Soldering



Maße werden wie folgt angegeben: mm (inch) / Dimensions are specified as follows: mm (inch)

Revision History: 2002-03-14

Previous Version: 2001-02-13

Page	Subjects (major changes since last revision)
3	thermal resistance (footnote)
4	value (wavelength amber/yellow/orange)

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